NSN 5961-01-425-0420

A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-425-0420 **Inclosure Material:** Plastic **Overall Length:** 0.210 inches **Overall Diameter:** 0.205 inches **Function For Which Designed:** Rectifier **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage and 200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 5.00 milliamperes forward current, total rms peak and 0.80 amperes forward current, total rms horsepower metric **Special Features:** Sensitive gate to-92 package; halfwave unidirectional gate controlled rectifier (scr thyristor) Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: